



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:)	PATENT APPLICATION
Inventors: Jong-Jan Lee and Sheng Teng)	
Hsu)	
Serial No.: 10/625,065)	Attorney Docket No.
Filed: July 22, 2003)	SLA0696
Title: FABRICATION OF SILICON-ON-)	Customer No. 27,518
NOTHING (SON) MOSFET)	
FABRICATION USING)	
SELECTIVE ETCHING OF)	
Si _{1-x} Ge _x LAYER)	

CERTIFICATE OF MAILING UNDER 37 C.F.R. § 1.8

I hereby certify that this correspondence is being deposited in the United States Postal Service with sufficient postage as first class mail in an envelope addressed to **Commissioner for Patents, Alexandria, VA 22313-1450** on January 14, 2004:

Victoria A. Woods
Signature Date : January 14, 2004

STATUS INQUIRY

Hon. Commissioner for Patents
Alexandria, VA 22313-1450

Sir:

Applicants have not received a filing receipt for the above-identified application. Accordingly, applicants' attorney-of-record, whose name and address appear below, hereby inquires as to the status of the above-identified application.

Please direct all correspondence in this application to the following:

David C. Ripma, Patent Counsel
Sharp Laboratories of America, Inc.
5750 NW Pacific Rim Boulevard
Camas, WA 98607
Telephone: (360) 834-8754
Facsimile: (360) 817-8505

Respectfully submitted,

Date: 01-14-04

By: David C. Ripma
David C. Ripma
Reg. No. 27,672

David C. Ripma, Patent Counsel
Sharp Laboratories of America, Inc.
5750 NW Pacific Rim Boulevard
Camas, WA 98607
Telephone: (360) 834-8754
Facsimile: (360) 817-8505